#### C7LC''\$+7!%\$A<n!F!J

Ultra Low Power High Stability Miniature OCXO

### Features and Benefits

10 MHz; +5V

14-pin DIP Compatible footprint

8.8 mm max. Height

Less than +/- 5 ppb over -20°C to +85°C Less than +/- 50 ppb per year aging

Less than 0.18 Watts typ. @+25°C after 60 second warmup

+5 dBm min. Output

Less than 1 ppb/G; 0.5 ppb/G is ordering option

## Typical Applications

Specially designed for SATCOM earth station, manpack, and portable transceiver platforms.

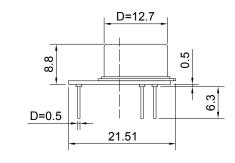
#### Description

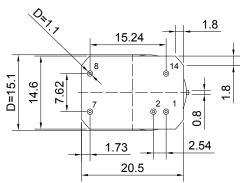
The OCXO3307C incorporates internal heating resonator technology with the entire oven control mechanical structure packaged inside the TO-8 vacuum holder. This design offers a drastic reduction in volume, power consumption, and warm-up time while still maintaining outstanding frequency stability and phase noise performance normally associated with devices in much larger enclosures.

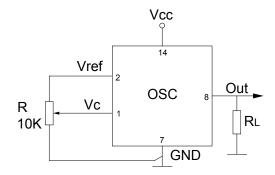
## Mechanical Drawing & Pin Connections

**Drawing No:** 

MD140076-1







Pin	Signal
1	Electrical tuning
2	Reference voltage
7	GND
8	RF Out
14	+V Supply

Unit: mm 1mm=0.039inch



# Dynamic Engineers Inc.

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Ultra Low Power High Stability Miniature OCXO

## **Specifications**

Oscillator	Sym	Condition	Value			11-24	Nata		
Specification			Min.	Тур.	Max.	Unit	Note		
Frequency	F <sub>0</sub>			10		MHz			
RF Output									
Waveform :				Sine-wave					
Level		Vcc=5V	+5	+8		dBm			
Load				50		Ohm			
Harmonics					-25	dBc			
Sub-harmonics level				None					
Frequency control									
Control voltage range	V <sub>c</sub>		0		4.2	V			
Frequency Turning Range			+/-0.5		-	ppm			
Reference Voltage	$V_{ref}$			4.2		V			
Power Supply									
Voltage	V <sub>cc</sub>		4.75	5	5.25	V			
		Warm-up state		1.0					
Power consumption		@ +25°C steady state after 60s		0.18		W			
Warm-up Time:	$T_{up}$	to Δf/f = 1e <sup>-7</sup> at +25°C ref. to frequencyafter 15 min		60		s			
Frequency Stability									
Vs.Temperature		-20°C to +85°C, ref. 25°C			+/-5	ppb			
Vs. Supply Voltage		Ref Vcc typ.		+/-2		ppb			
vs. Acceleration		worst direction			+/-1	ppb/G	0.5ppb/G optionally		
A sin s		after 30days of operation		+/-0.5		ppb			
Aging First year				+/-50		ppb			
, ,		1 Hz		-100					
		10 Hz		-135					
Phase noise@10MHz		100 Hz		-159		dBc/Hz			
_		1 KHz		-166		UBC/HZ			
		10KHz		-170					
		100 KHz		-170					
Environmental Conditions									
Storage temperature range	-60°C to 90°C								
Operating temperature range	-20°C to 85°C								
Humidity	Non-condensing 95%								
Mechanical Shock	MIL-STD-202, 30G half sine pulse, 11 ms								
Vibration		MIL-STD-202, 5G swept sine, 10 to 2000 Hz							
	MIL-STD-	202, 5G swept sine, 10 to 2000	Hz						
Washing Conditions Soldering Conditions	Washing v	202, 5G swept sine, 10 to 2000 with water or alcohol based deternance only – not reflow compatible	ergent allow	ed only with fir	nal enough	drying stage			